

## 产品规格书

### Specifcation of products

产品名称:肖特基二极管

产品型号: MBDK600U45NK4

浙江世菱半导体有限公司  
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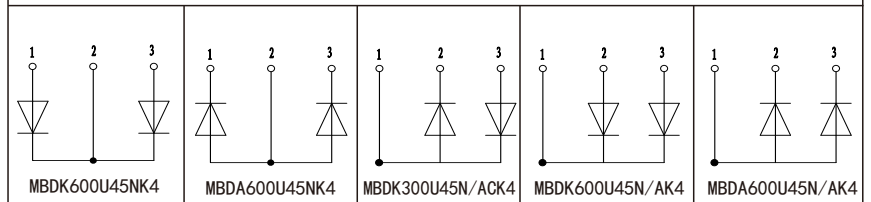
### PRODUCT FEATURES

- ☑ Ultrafast Reverse Recovery Time
- ☑ Soft Reverse Recovery Characteristics
- ☑ Low Reverse Recovery Loss
- ☑ Low Forward Voltage
- ☑ High Surge Current Capability
- ☑ Low Inductance Package



### APPLICATIONS

- ☑ Inversion Welder
- ☑ Uninterruptible Power Supply (UPS)
- ☑ Plating Power Supply
- ☑ Ultrasonic Cleaner and Welder
- ☑ Converter & Chopper
- ☑ Power Factor Correction (PFC) Circuit



### ABSOLUTE MAXIMUM RATINGS

$T_C=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
$V_R$	Maximum D.C. Reverse Voltage		45	V
$V_{RRM}$	Maximum Repetitive Reverse Voltage		45	V
$I_{F(AV)}$	Average Forward Current	$T_C=100^{\circ}\text{C}$ , Per Diode	300	A
		$T_C=100^{\circ}\text{C}$ , Per Module	600	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=100^{\circ}\text{C}$ , Per Diode	420	A
$I_{FSM}$	Non-Repetitive Surge Forward Current	1/2 Cycle, 60Hz, Sine	6600	A
$I^2t$	$I^2t$ (For Fusing)	$T_J=45^{\circ}\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	130050	$\text{A}^2\text{s}$
$P_D$	Power Dissipation		225	W
$T_J$	Junction Temperature		-40 to +150	$^{\circ}\text{C}$
$T_{STG}$	Storage Temperature Range		-40 to +125	$^{\circ}\text{C}$
$V_{iso}$	Insulation Test Voltage	AC, $t=1\text{min}$	3000	V
Torque	Module-to-Sink	Recommended (M6)	3~5	N.m
Torque	Module Electrodes	Recommended (M6)	3~5	N.m
$R_{\theta JC}$	Thermal Resistance	Junction-to-Case	0.12	$^{\circ}\text{C}/\text{W}$
Weight			155	g

### ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I <sub>RM</sub>	Reverse Leakage Current	V <sub>R</sub> =45V	--	--	0.3	mA
		V <sub>R</sub> =45V, T <sub>J</sub> =125°C	--	--	2	mA
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> =300A	--	0.50	--	V
		I <sub>F</sub> =300A, T <sub>J</sub> =125°C	--	0.45	--	V

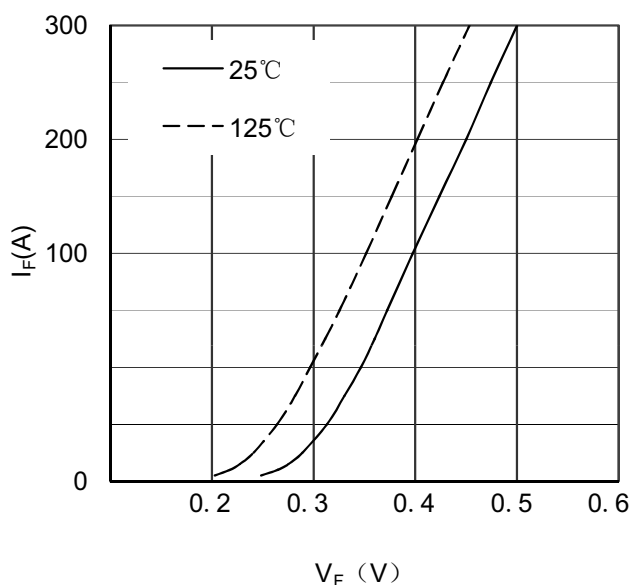


Figure 1. Forward Voltage Drop vs Forward Current

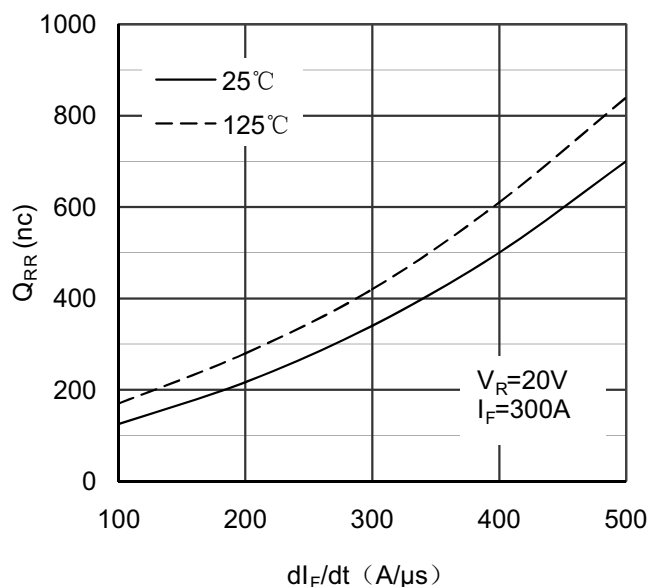


Figure 2. Reverse Recovery Charge vs di<sub>F</sub>/dt

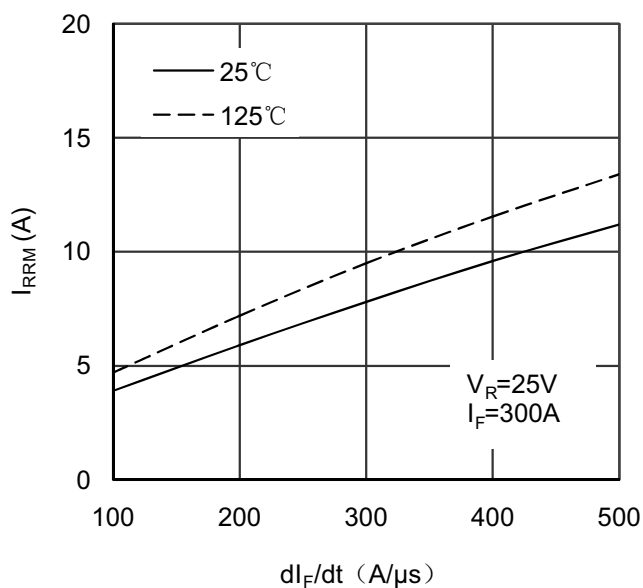


Figure 3. Reverse Recovery Current vs di<sub>F</sub>/dt

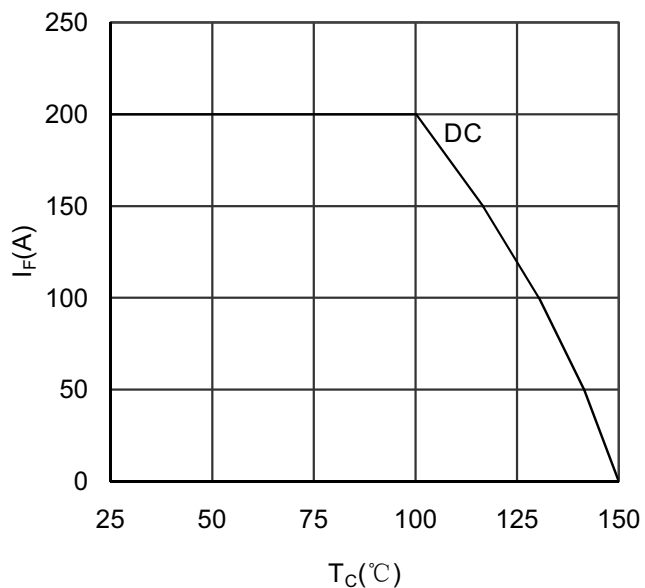


Figure 4. Forward current vs Case temperature

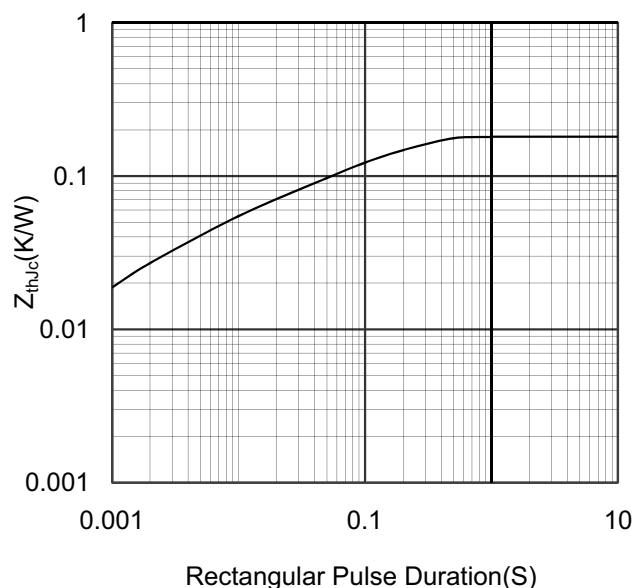
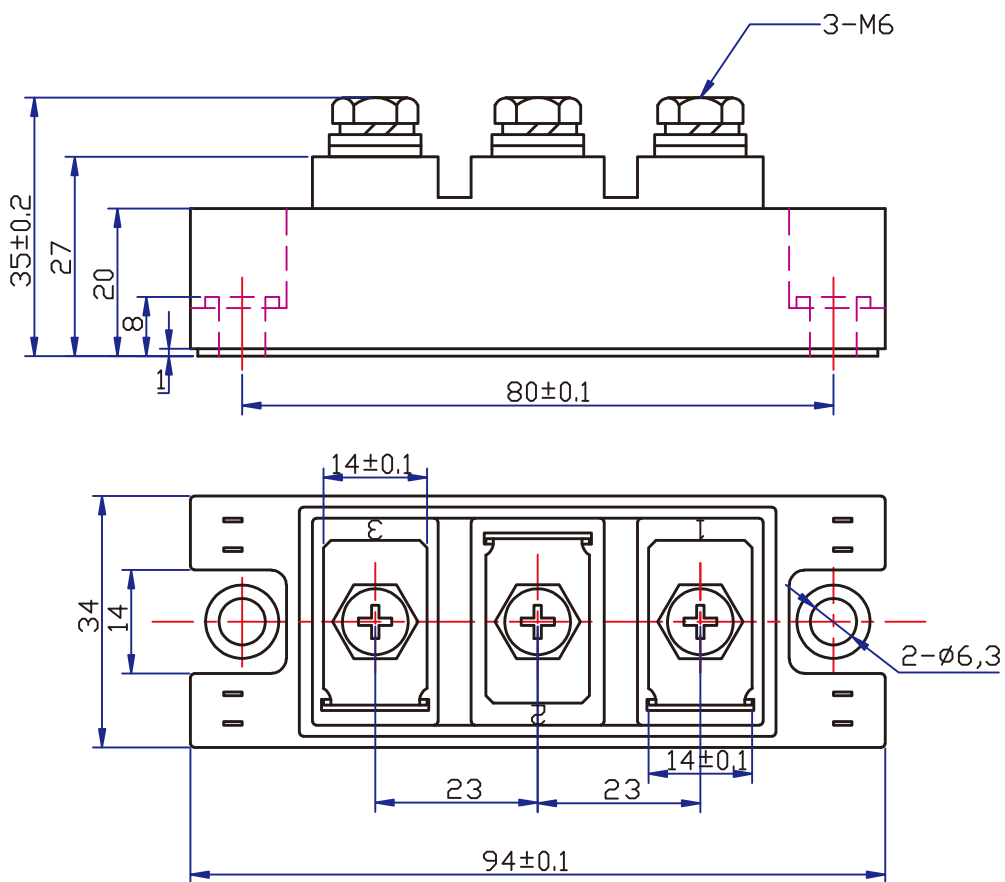


Figure 5. Transient Thermal Impedance

## Package Outlines



Unit:mm